

CSET102

Tutorial Sheet - 8 (Solutions)

SNO	Answers
1	<p>Given $I_D = 150 \mu A$ $I_S = 10^{-11} A$ $V_D = ?$</p> $V_D = V_T \ln\left(\frac{I_D}{I_S} + 1\right) = \underline{0.43V}$
2	<p>Given $I_D = -0.9 I_S$ $V_D = ?$</p> $-0.9 I_S = I_S \left(e^{\frac{V_D}{V_T}} - 1 \right) \quad V_T = 0.026V = 26 mV$ $V_D = \underline{-0.06V}$ <p>(\because in reverse bias I_D is opposite to that of original current direction)</p> <p>$I_D = 0.9 I_S$ results $V_D = +0.017V$ which is forward bias.</p>

3

$$V_D = 0.2 \text{ V} \quad I_D = I_S (e^{V_D/V_T} - 1) = 2192.4 I_S$$

$$V_D = -0.2 \quad I_D = -0.9995 I_S$$

$$\left| \frac{I_D @ 0.2 \text{ V}}{I_D @ -0.2 \text{ V}} \right| = \underline{2193.4}$$

4



Given $V = 0.7 \text{ V}$

(i) Applying KVL, $V_{R1} = 2 - 0.7 = 1.3 \text{ V}$

$$V_{R2} = 0.7 \text{ V}$$

$$V_{R2} = \frac{2 \cdot R_2}{R_1 + R_2} = 0.7 \text{ V}$$

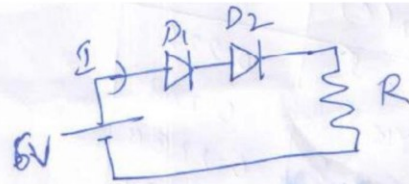
$$R_2 = 0.35 R_1 + 0.35 R_2 \Rightarrow R_2 = \underline{538 \Omega}$$

ii) $R_2 = 1 \text{ k}\Omega$

$$V_{R2} = 0.7 \text{ V} = \frac{2 \cdot R_2}{R_1 + R_2} \Rightarrow R_2 = 0.35 R_1 + 0.35 R_2$$

$$\Rightarrow R_1 = \underline{1.86 \text{ k}\Omega}$$

5



$$I = 15 \mu\text{A}$$

$$I_0(D_1) = 5 \text{ nA}$$

$$I_0(D_2) = 10 \text{ nA}$$

$$I = I_0 \left(e^{V_D / V_T} - 1 \right) \Rightarrow V_D = V_T \ln \left(\frac{I}{I_0} + 1 \right)$$

$$V_T = 26 \text{ mV at } 300 \text{ K}$$

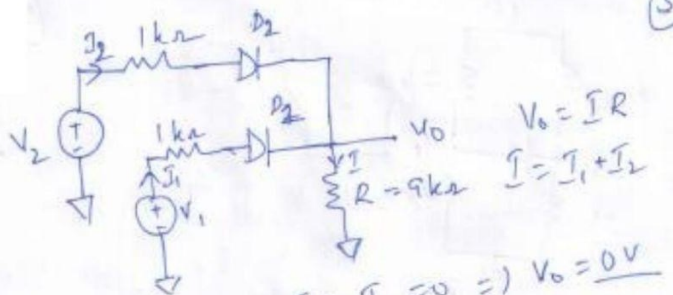
$$\text{for } D_1: V_{D1} = 0.026 \ln \left(\frac{15 \times 10^{-6}}{5 \times 10^{-9}} + 1 \right) = 0.388 \text{ V}$$

$$\text{for } D_2: V_{D2} = 0.37 \text{ V}$$

$$\text{Applying KVL, } 6 = 0.388 + 0.37 + I \cdot R$$

$$\Rightarrow R = \underline{350 \Omega}$$

6



$$V_0 = I R$$

$$I = I_1 + I_2$$

$$(i) V_1 = V_2 = 0 \Rightarrow I_1 = I_2 = 0 \Rightarrow V_0 = 0 \text{ V}$$

$$(ii) V_1 = 10 \text{ V } V_2 = 0 \Rightarrow I_2 = 0, I_1 = ?$$

$$I = I_1 + I_2 = I_1$$

Applying KVL,

$$I_1 = \frac{10 - 0.6}{1 \text{ k} + 9 \text{ k}} = 0.94 \text{ } \mu\text{A}$$

$$V_0 = I \cdot R = 0.94 \times 9 \text{ k} = \underline{8.46 \text{ V}}$$

$$(iii) V_1 = 10 \text{ V } V_2 = 10 \text{ V}$$

$$I_1 = I_2 \quad I = I_1 + I_2 \Rightarrow I_1 = I_2 = \frac{I}{2}$$

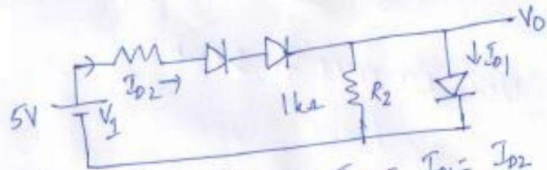
writing KVL,

$$10 = \frac{I}{2} \times 1 \text{ k} + 0.6 + I \cdot 9 \text{ k}$$

$$9.5 \text{ k} \cdot I = 9.4 \Rightarrow I = 0.989 \text{ mA}$$

$$V_0 = I R = 0.989 \times 9 = \underline{8.91 \text{ V}}$$

7)



given $I_{D1} = \frac{I_{D2}}{2} \Rightarrow I_{R2} = I_{D1} = \frac{I_{D2}}{2}$

$$I_{D1} = I_{R2} = \frac{0.65V}{1k\Omega} = 0.65mA$$

$$\therefore I_{D2} = 1.3mA$$

(i) Applying KVL, $I_{D2} = \frac{V_S - 2V_D - V_0}{R_1}$

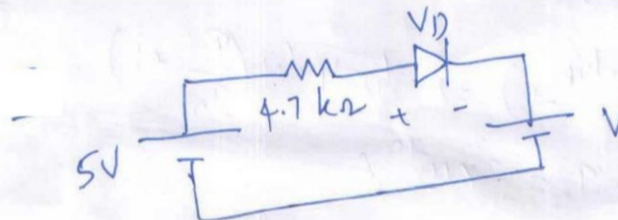
$$\Rightarrow R_1 = \frac{1.3 \times 10^{-3} R_1}{5 - 2 \times 0.65 - 0.65} \Rightarrow R_1 = 2.35k\Omega$$

(ii) $V_D = 8V$ $I_{R2} = 0.65mA$

$$I_{D2} = \frac{8 - 2 \times 0.65 - 0.65}{2k\Omega} = 3.025mA$$

$$I_{D1} = I_{D2} - I_{R2} = 2.375mA$$

8)



$$V_D = 0.7V$$

$$I_D = 0.4mA$$

Writing KVL,

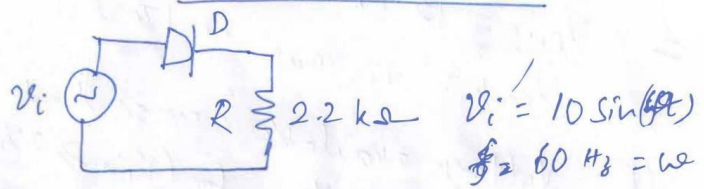
$$5 = 4.7k I_D + 0.7 + V$$

$$\Rightarrow V = 2.42V$$

$$2.42V$$

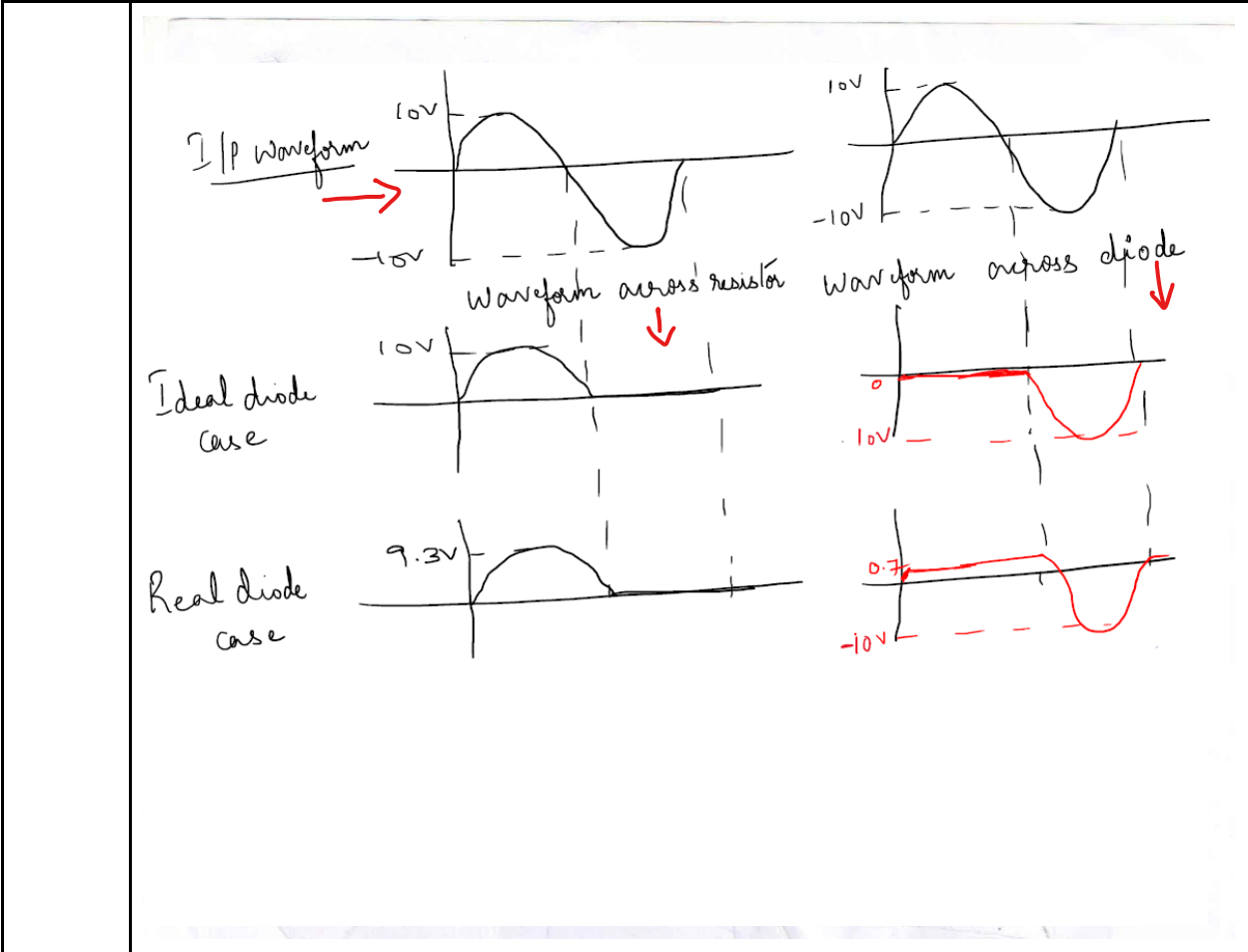
$$P = V \times I = 0.7V \times 0.4mA = 0.28mW$$

9)



Ideal diode: no voltage drop in forward bias. So voltage drops across R entire voltage drops across D in reverse bias.

Real diode, V_D is fixed at 0.7 V (for Si)
when, $v_i \geq 0.7$ then $v_D = v_i$



10)

